Preferred Device

Small Signal MOSFET 200 mAmps, 60 Volts

N-Channel TO-92

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	VDSS	60	V
Drain-Gate Voltage	VDGR	60	V
Gate—Source Voltage — Continuous — Non–repetitive ($t_p \le 50 \mu s$)	V _{GS} V _{GSM}	± 20 ± 40	Vdc Vpk
Continuous Drain Current	ΙD	200	mA
Pulsed Drain Current	I _{DM}	500	mA
Power Dissipation @ T _C = 25°C Derate above 25°C	PD	350 2.8	mW mW/°C
Operating and Storage Temperature	TJ, T _{stg}	-	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	312.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/16" from case for 10 seconds	TL	300	°C

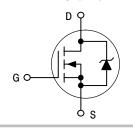


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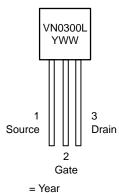
http://onsemi.com

200 mAMPS 60 VOLTS RDS(on) = 1.2 Ω

N-Channel







WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping	
VN0300L	TO-92	1000 Units/Box	
VN0300LRLRA	TO-92	2000 Tape & Reel	
VN0300LRLRE	TO-92	2000 Tape & Reel	

Preferred devices are recommended choices for future use and best overall value.

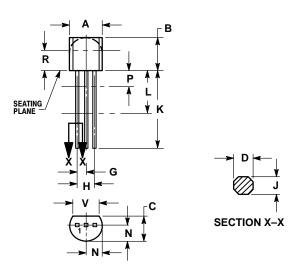
ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)

•	Symbol	Min	Max	Unit	
STATIC CHARACTERISTICS		1			
Drain–Source Breakdown Voltage (V _{DS} = 0, I _D = 10 μA)		V(BR)DSS	30		V
Zero Gate Voltage Drain Current (VDS = 48 Vdc, VGS = 0) (VDS = 48 Vdc, VGS = 0, TA = 125°C)		IDSS	- -	10 500	μΑ
Gate–Body Leakage (V _{DS} = 0, V _{GS} = ±30 V)	lGSS	-	±100	nA	
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 1.0 mA)	VGS(th)	0.8	2.5	V	
On-State Drain Current (Note 1.) (V _{DS} = V _{GS} , I _D = 1.0 mA)	I _{D(on)}	1.0	-	А	
Drain–Source On Resistance (Note 1.) ($V_{GS} = 5.0 \text{ V}$, $I_D = 0.3 \text{ A}$) ($V_{GS} = 10 \text{ V}$, $I_D = 1.0 \text{ A}$)		rDS(on)	_ _	3.3 1.2	Ω
Forward Transconductance (Note (V _{DS} = 10 V, I _D = 0.5 A)	9fs	200	-	mS	
DYNAMIC CHARACTERISTIC	s			•	•
Input Capacitance		C _{iss}	_	100	pF
Output Capacitance	$(V_{DS} = 15 \text{ Vdc}, V_{GS} = 0, \\ f = 1.0 \text{ MHz})$	C _{oss}	_	95	pF
Reverse Transfer Capacitance	· ···-,	C _{rss}	_	25	pF
SWITCHING CHARACTERIST	rics				
Turn-On Time	(V _{DD} = 25 Vdc, I _D = 1.0 A,	ton	_	30	ns
Turn-Off Time	$R_L = 24 \Omega$, $RG = 25 \Omega$)	toff	-	30	ns

^{1.} Pulse Test; Pulse Width < 300 μ s, Duty Cycle \leq 2.0%.

PACKAGE DIMENSIONS

TO-92 CASE 29-11 ISSUE AL



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES MILLIMETER		IETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0 135		3 43	

STYLE 22:
PIN 1. SOURCE
2. GATE
3. DRAIN

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